

## Surface Mount General Purpose Silicon Rectifiers

Reverse Voltage - 50 to 1000 V Forward Current - 3 A

### FEATURES

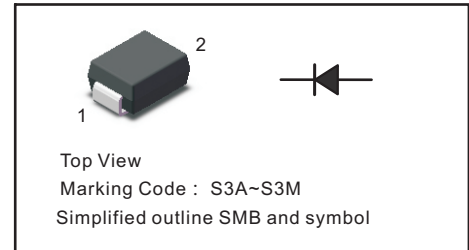
- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

### MECHANICAL DATA

- Case: SMB
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.055g / 0.002oz

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

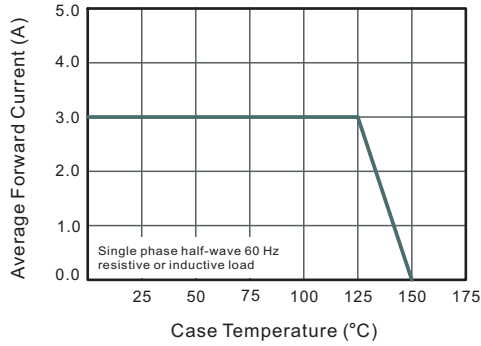
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	S3AB G	S3BB G	S3DB G	S3GB G	S3JB G	S3KB G	S3MB G	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	3							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	90							A
Maximum Instantaneous Forward Voltage at 3 A	$V_F$	1.1							V
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^\circ\text{C}$	$I_R$	5 100							$\mu\text{A}$
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	35							pF
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$ $R_{\theta JC}$	48 16							$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150							$^\circ\text{C}$

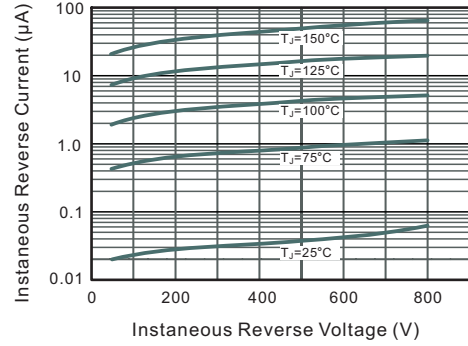
( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

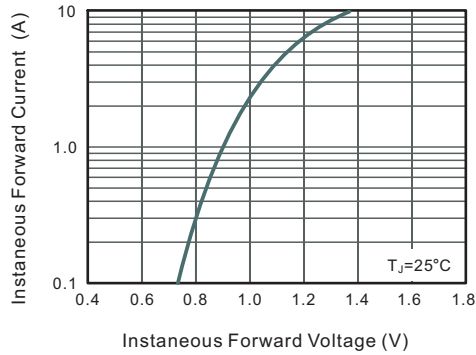
**Fig.1 Forward Current Derating Curve**



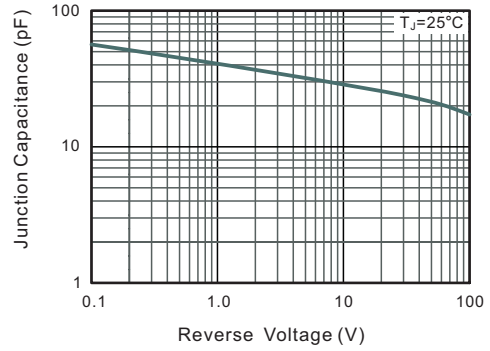
**Fig.2 Typical Instantaneous Reverse Characteristics**



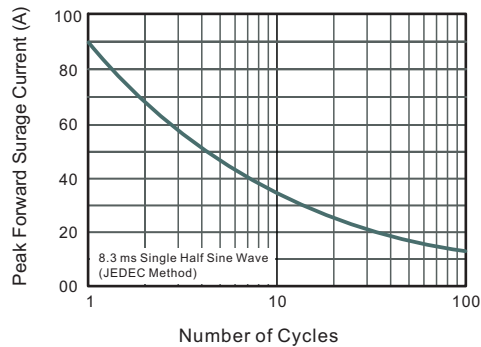
**Fig.3 Typical Forward Characteristic**



**Fig.4 Typical Junction Capacitance**



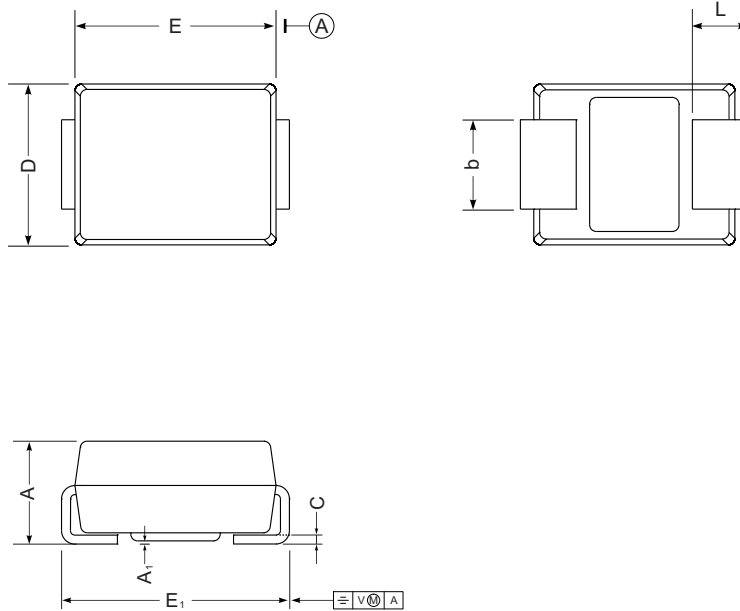
**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

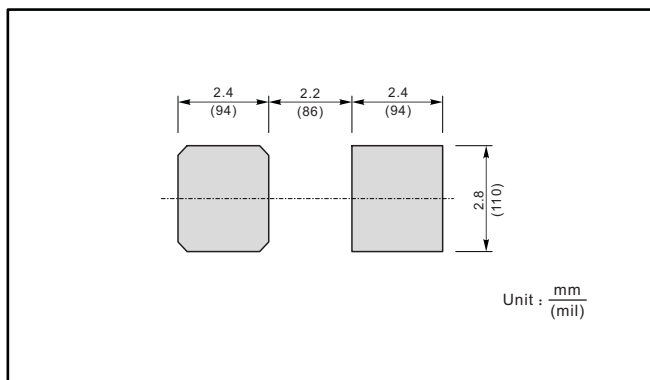
SMB



SMB mechanical data

UNIT		A	E	D	E <sub>1</sub>	A <sub>1</sub>	L	C	b
mm	max	2.44	4.70	3.94	5.59	0.20	1.5	0.305	2.2
	min	2.13	4.06	3.3	5.08	0.05	0.8	0.152	1.9
mil	max	96	185	155	220	7.9	59	12	87
	min	84	160	130	200	2.0	32	6	75

### The recommended mounting pad size



### Marking

Type number	Marking code
S3ABG	S3A
S3BBG	S3B
S3DBG	S3D
S3GBG	S3G
S3JBG	S3J
S3KBG	S3K
S3MBG	S3M

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